EAST Search History

EAST Search History (Prior Art)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S35	6	(("6891236") or ("20050074963") or ("6323143")).PN.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/12/02 09:22
S37	414	light and pixel and (Ti titanium W tungsten Cr chromium Ta tantalum Ni nickel Mo molybdenum metal) and (gate with (particles nano \$1particles)) and (insulat \$3 dielectric) and ((silicon near nitride) (SiN "Si. sub.3N.sub.4") (silicon near oxide) SiNO SiON SiOxyN) and ((silicon near oxide) SiO.sub.2")	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/12/02 12:47
S36	1474	(Ti titanium W tungsten Cr chromium Ta tantalum Ni nickel Mo molybdenum metal) and (gate with (particles nano \$1particles)) and (insulat \$3 dielectric) and ((silicon near nitride) (SiN "Si. sub.3N.sub.4") (silicon near nitride near oxide) SiNO SiON SiOxyN) and ((silicon near oxide) SiO.sub.2")	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2009/12/02 12:47
S40	4	(("20020179906") or ("5947783")).PN.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/12/02 14:16
S41	3728	(257/59).CCLS.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/12/02 14:40

S42	3659	(257/72).CCLS.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/12/02 14:41
S43	2164	(257/E29.151).CCLS.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/12/02 14:43
S48	453	(257/E27.152).CCLS.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/12/02 14:45
S47	2456	(257/E27.132).CCLS.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/12/02 14:45
S46	1502	(257/E27.131).COLS.	US-PGPUB; USPAT; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2009/12/02 14:45

EAST Search History (Interference)

Ref#	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S38	0	(light and pixel and (Ti titanium W tungsten Cr chromium Ta tantalum Ni nickel Mo molybdenum metal) and (gate with (particles nano\$1particles)) and (insulat\$3 dielectric) and ((silicon near nitride) (SiN "Si.sub.3N. sub.4") (silicon near nitride near oxide) SiNO SiON SiOxyN) and ((silicon near oxide) SiO "SiO.sub.2")).clm.	USPAT; UPAD	OR	ON	2009/12/02 12:42

S39	18	((Ti titanium W tungsten Cr chromium Ta tantalum Ni nickel Mo molybdenum metal) and (gate with (particles nano\$1particles)) and (insulat\$3 dielectric) and ((silicon near	USPAT; UPAD	OR	ON	2009/12/02 12:43
		nitride) (SiN "Si.sub.3N. sub.4") (silicon near nitride near oxide) SiNO SiON SiOxyN) and ((silicon near oxide) SiO "SiO.sub.2")).clm.				

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